# **MUR460G**

### Fast Recovery Rectifiers Reverse Voltage – 600 V Forward Current – 4 A

## Features

- Glass passivated die construction
- Super fast recovery time for high efficiency
- · Low forward voltage drop and high current capability

### **Mechanical Data**

- Case: Molded plastic, DO-201AD
- Terminals: Solder plater terminal, solderable per MIL-STD-202, method 208 guaranteed
- Polarity: Cathode Band
- Mounting position: Any



## **Absolute Maximum Ratings and Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	MUR460G	Units
	Marking	MUR460G	-
Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	600	V
Working Peak Reverse Voltage	V <sub>RWM</sub>	600	V
DC Blocking Voltage	V <sub>R</sub>	600	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	424	V
Average Rectified Output Current at $T_T = 40^{\circ}C$	I <sub>F(AV)</sub>	4	A
Peak Forward Surge Current, 8.3 ms Single Half-sine-wave Superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	70	A
Forward Voltage at $I_F = 3 A$ , $T_j = 150^{\circ}C$ at $I_F = 3 A$ , $T_j = 25^{\circ}C$ at $I_F = 4 A$ , $T_j = 25^{\circ}C$	V <sub>F</sub>	1.05 1.25 1.28	V
Reverse Current at Rated $T_a = 25^{\circ}C$ DC Blocking Voltage $T_a = 150^{\circ}C$	I <sub>R</sub>	10 250	μA
Reverse Recovery Time <sup>1)</sup>	t <sub>rr</sub>	50	ns
Junction Capacitance <sup>2)</sup>	CJ	75	pF
Thermal Resistance 3)	R <sub>θJA</sub>	52	K/W
Operating Junction and Storage Temperature Range	$T_{J,}T_{Stg}$	-65 to +175	٦°

<sup>1)</sup> Measured with  $I_F$  = 0.5 A,  $I_R$  = 1.0 A,  $I_{rr}$  = 0.25 A.

 $^{\rm 2)}$  Measured at 1.0 MHz and applied reverse voltage of 4 V DC.

<sup>3)</sup> Mounted to PCB, lead length = 9.5 mm.









Dated : 06/11/2015 Rev:02





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